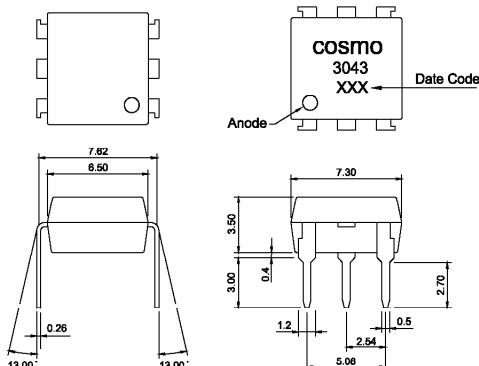
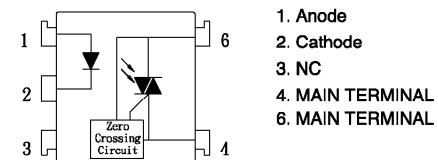


**For 115/240 Vac (rms) Application:**

1. Solenoid/Valve Controls.
2. Lighting Controls.
3. Static Power Switches.
4. AC Motor Drives.
5. Temperature Controls.
6. E. M. Contactors.
7. AC Motor Stators.
8. Solid State Relays.

**Outside Dimension:Unit (mm)****Schematic:Top View****Absolute Maximum Ratings**

(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	50	mA
	Peak forward current	I <sub>FM</sub>	1	A
	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	P <sub>D</sub>	70	mW
Output	Off-State Output Terminal voltage	V <sub>DRM</sub>	400	Vpeak
	Peak Repetitive Surge Current	I <sub>TSM</sub>	1	A
	Power dissipation	P <sub>D</sub>	300	mW
	Total power dissipation	P <sub>tot</sub>	330	mW
	Isolation voltage 1 minute	V <sub>iso</sub>	5000	Vrms
	Operating temperature	T <sub>opr</sub>	-40 to +80	°C
	Storage temperature	T <sub>stg</sub>	-40 to +125	°C
Soldering temperature 10 seconds		T <sub>sol</sub>	260	°C

**Electro-optical Characteristics**

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> =10mA	—	1.2	1.4	V
	Reverse Leakage Current	I <sub>R</sub>	V <sub>R</sub> =4V	—	—	10	μA
Output	Peak Blocking Current	I <sub>DRM</sub>	V <sub>DRM</sub> =Rated	—	60	500	nA
	ON-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> =100mA	—	1.8	3	V
	Critical rate of rise of OFF-state voltage	dV/dt	V <sub>DRM</sub> =(1/√2 ) * Rated	600	—	—	V/μS
Transfer characteristics	Holding Current	I <sub>H</sub>		—	100	—	μA
	Inhibit Voltage (MT1-MT2 Voltage above which device not trigger.)	V <sub>INH</sub>	I <sub>F</sub> =5mA	—	5	20	V
	Leakage in Inhibited State	I <sub>DRM2</sub>	I <sub>F</sub> =Rated I <sub>FT</sub> , Rated V <sub>DRM</sub> , Off State	—	—	500	μA
	Isolation resistance	R <sub>iso</sub>	DC500V	5x10 <sup>10</sup>	10 <sup>11</sup>	—	ohm
	Minimum trigger current	I <sub>FT</sub>	Main Terminal Voltage=3V	—	—	5	mA

